## THz generation and Ultrafast Electron Diffraction at PITZ

M. Krasilnikov, DESY, Zeuthen, Germany



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## Photo Injector Test facility at DESY in Zeuthen (PITZ)

#### Main Goals:

- provide optimized electron sources (minimum emittance) for FLASH and European XFEL
- do general accelerator R&D

#### **Research areas:**

DESY.

- basic photo injector R&D
- specific R&D for FLASH & European XFEL (for current facilities and future upgrades → e.g. CW upgrade of European XFEL)
- application of high brightness electron beams + general accelerator R&D for novel acceleration techniques
  → applications like THz, plasma acceleration, UED, …





## **PITZ "engine": RF-Gun and Photocathode Laser**

Highlights of the facility



- L-band (1.3 GHz) 1.6-cell copper cavity
- Ecath>~60MV/m → 7MeV/c e-beams
- 650us x 10Hz → up to 45 kW av. RF power
- $Cs_2Te$  PC (QE~5-10%)  $\rightarrow$  up to 5nC/bunch
- LLRF control for amp&phase stability
- Solenoids for emittance compensation





## Photocathode laser(s) (UV)

**Default laser system** 

(Max-Born-Institute, Berlin)

Gaussian:



# **THz at PITZ**

## **IR/THz SASE source for pump-probe experiments @E-XFEL**

PITZ-like accelerator can enable high power, tunable, synchronized IR/THz radiation



## **IR/THz Options at PITZ: High-gain THz SASE FEL**

Case studies of generating THz radiation by PITZ electron beam



## **THz SASE FEL at PITZ**





#### SASE FEL simulations assuming:

- Helical undulator with period length of 40 mm
- Electron beam with 15 MeV/c momentum, 4 nC bunch charge, ~2 mm rms bunch length

#### Preliminary conclusions:

- Transverse normalized emittance  $\varepsilon_n$  has almost no impact on saturation power
- Beam **peak current** (charge) → most impact

## THz SASE FEL: Simulations for $\lambda_{rad}$ = 100 µm (3 THz)



## **Options to improve THz radiation stability**

Pre-bunching to improve CEP stability of SASE → "Seeding"

- Photocathode laser pulse temporal modulation
- Using IR laser, modulator and BC for E or  $\delta E$  modulations
- Using CDR from short seeding bunch
- Using corrugated structures
- Using Dielectric Lined Waveguides DLW (first experiments)



#### **E-beam current profile** without (blue trace) with DLW (red trace), $\lambda$ =1.03 mm; The peaks are consistent with the wavelength of the structure 3.3 ps. 0.8 $\widehat{\operatorname{mits}}$ 0.6 ~120 A $\overset{\rm larp}{\underbrace{}_{0.4}}$ current 0.2 ~60 A 0.0 10-15-10-50 515time (ps)



*F.* Lemery et al., Passive Ballistic Microbunching of Nonultrarelativistic Electron Bunches Using Electromagnetic Wakefields in Dielectric-Lined Waveguides, Phys. Rev. Lett., 122 044801 (2019)



## **Proof-of-principle experiment on THz SASE FEL at PITZ**

Using LCLS-I undulators (available on loan from SLAC) → under implementation

#### Some Properties of the LCLS-I undulator

Properties	Details
Туре	planar hybrid (NdFeB)
K-value	3.585 (3.49)
Support diameter / length	30 cm / 3.4 m
Vacuum chamber size	11 mm x 5 mm
Period length	30 mm
Periods / a module	113 periods





Reference: LCLS conceptual design report, SLAC-0593, 2002.

 $\lambda_{rad}$ ~100 $\mu$ m  $\rightarrow$  <Pz>=17.05MeV/c

#### Preliminary conclusions on LCLS-I undulators at PITZ:

- Might be not such extremely high performance as for the APPLE-II, but is clearly proper for the proof-of-principle experiment!
- 4 nC electron beam transport through the vacuum chamber needs efforts, but seems to be feasible.

## Start-to-end simulations for proof-of-principle experiment at PITZ

PITZ main tunnel and tunnel annex for the LCLS-I undulator installation

- Radiation shielding is improved (based on FLUKA simulations of Zohrab Amirkhanyan, CANDLE)
- Preparation for operation permission for annex is ongoing



#### S2E simulations: from photocathode $\rightarrow$ undulator $\rightarrow$ THz SASE FEL

#### Main challenges:

- 4 nC (~200A) x 17.05MeV/c  $\rightarrow$  SC dominated beam
- ~30 m transport (incl. 1.5 m wall)  $\rightarrow$  LCLS-I undulator in the tunnel annex
- 3D field of the undulator
- Matching into the planar undulator (narrow vacuum chamber issue)

#### Tools:

- ASTRA
- SC-Optimizer
- GENESIS 1.3

## Start-to-end simulation with flattop photocathode laser

**Optimization of the photo-injector (~5m) + Design of transport line (~27m)** 

- For the photo-injector optimization
- Laser
  - Flattop longitudinally: 21.5 ps
  - Uniform and tunable transversely: < 5 mm
- Gun: highest gradient achievable: Ecath=60 MV/m
- Other tunable parameters: Gun phase, Booster phase, Solenoid current

$$\rho = \left[\frac{1}{16} \frac{I_{\text{peak}}}{I_A} \frac{K_0^2 [JJ]^2}{\gamma^3 \sigma_x^2 k_u^2}\right]^{1/3} \qquad \qquad \frac{\varepsilon_n}{\beta \gamma} \le \frac{\lambda_s}{4\pi} \to \varepsilon_n \le 200 \mu \text{m}$$

- Goal function:  $F = f(\langle \varepsilon_n \rangle, \sigma_E^{\text{corr}})$ 
  - Beam momentum 17.05 MeV/c <= booster gradient
  - Minimizing emittance oscillation after the booster
  - Minimizing correlated energy spread  $\operatorname{cor}_{E_k} = \langle zE_k \rangle / \sigma_z$  at the undulator
- Results: many solutions with different laser spot sizes



## **LCLS-I undulator field modeling**

Using By(0,0,z) field profile measurements done on 02.10.2013 at SLAC for the undulator L143-112000-07 after the final tuning

$$B_{y}(x=0, y=0, z) = \sum_{n=0}^{\infty} \left\{ a_{n} \cos\left(\frac{2\pi nz}{N_{U}\lambda_{U}}\right) + b_{n} \sin\left(\frac{2\pi nz}{N_{U}\lambda_{U}}\right) \right\}$$

**3D field map** generation (to be used as external field map for ASTRA (static magnetic cavity), CST(Trk/PIC) and LW code):

$$B_{y}(x, y, z) = \sum_{n=1}^{N_{h} \cdot N_{U}} \left[ \left\{ \tilde{a}_{n} \cos(k_{n}z) + \tilde{b}_{n} \sin(k_{n}z) \right\} \cdot \cosh(k_{n}y) \right]$$
$$B_{z}(x, y, z) = \sum_{n=1}^{N_{h} \cdot N_{U}} \left[ \left\{ -\tilde{a}_{n} \sin(k_{n}z) + \tilde{b}_{n} \cos(k_{n}z) \right\} \cdot \sinh(k_{n}y) \right]$$





#### Trans. & long. phase spaces at undulator entrance 100 r 75 17.3

vacuum chamber of the undulator module

• Two quadrupole triplets to focus the beam when

Astra + SCO simulation

- passing through diagnostics sections
- Another two triplets to match the beam into the

Transport and matching of the beam to the undulator





z (m)

## Start-to-end simulation with flattop photocathode laser

(mm mrad)

### THz radiation generation

- Genesis 1.3 simulation
  - Beam from Astra simulation used as input
  - No transverse space charge effects
  - No waveguide effects

D=3.2 mm

600

500

 $\hat{J}^{400}$ 

ш<sub>300</sub>,

200

100



Parameter	Value	Unit
Pulse energy	493.1±108.8	μJ
Peak power	52.7±11.8	MW
Centre wavelength	101.8±0.7	μm
Spectrum width	2.0±0.4	μm
Arrival time jitter	1.45	ps





#### Pulse energy vs peak current D-photocathode laser spot diameter

150 155 160 165 170 175 180 *I*<sub>peak</sub> (A)

D=3.7 mm

## Plans in the PITZ tunnel annex: PITZ4 – Phase 1 (PITHz)

Beam line upgrade towards proof-of-principle experiments on THz generation



## **Experimental studies with Gaussian photocathode laser pulses**

High charge beam generation

- Laser distributions used for simulations
  - Flattop longitudinally: 21.5 ps
  - Uniform and tunable transversely: < 5 mm
- Actual laser distributions
  - Gaussian longitudinally: 6-7 ps FWHM
  - Gaussian truncated transversely: ~3 mm FWHM
- From the short (~6ps FWHM) Gaussian laser, it is possible to extract 4 nC bunch charge, but at the cost of strong saturation, which is difficult to model with Astra
- To suppress strong saturation, large BSA (4 mm) was used for bunch charge of 2.5 nC while maintaining high peak current

#### Emission curves for various BSA (laser spot) diameters



## **Experimental studies with Gaussian photocathode laser pulses**

High charge beam characterization

- At reduced bunch charge of **2.5 nC**, the beam has been characterized after acceleration & transportation
  - Laser: Gaussian longitudinally with FWHM of 6-7 ps and Gaussian truncated transversely with FWHM of ~3 mm
  - Gun: maximum accelerating gradient and MMMG phase => 6.6 MeV/c
  - Booster: MMMG -20 degree, gradient tuned => 17.05 MeV/c

Parameter	Meas.	Simul.	Unit
Laser FWHM	6.2	6	ps
Laser BSA	4	4	mm
Bunch charge	2.53±0.05	2.5	nC
Momentum	17.0	17	MeV/c
Peak current	153±0.5	156	А
xy emittance	3.90	4.14	mm mrad

#### Temporal bunch profile by TDS



#### Transverse phase spaces measured with slit-scan



## **Experimental studies with Gaussian laser pulses**

#### Transport and matching of the beam

• Matching with two quadrupole triplets in the existing beamline (2.5 nC)



#### Procedure:

- 1, Phase space matching at EMSY1
- 2, Tuning the first triplet
- 3, Tuning the second triplet

All based on simulation results

#### **Results:**

1. The beam was matched at PST.Scr1

2. Currents of triplets were different from simulated ones.

beam size

RMS

 $\sim\sim\sim\sim\sim\sim$ 

1.5

5 2.0 Z(m) 2.5

3.0

3.5

1.0

0.5

0.0

## First THz Radiation Generated at PITZ

Using CTR/CDR for THz generation (also for seeding?)

Coherent Transition / Diffraction Radiation (CTR/CDR) for  $\lambda_{rad} \ge 100 \mu m$  (f  $\le 3 THz$ )



## **PITZ Highlights:**

- Pulse train structure
- High charge feasibility (4 nC)
- Advanced photocathode laser shaping
- E-beam diagnostics
- Available tunnel annex
- . . .

PhD Thesis of P. Boonpornprasert "Investigations on the capabilities of THz production at the PITZ facility"

#### **Current PITZ "boundary conditions":**

- 22-25 MeV/c max
- No bunch compressor

• ...

## 1<sup>st</sup> experiments with **CTR/CDR THz generation**

#### Measured electron beam temporal profiles



#### **THz Michelson interferometer** measurements of CTR



# Ultrafast Electron Diffraction at PITZ?

## **Beam simulation of UED test at PITZ**

**Optimized for solid state samples** 

- Simulations of two operation modes
  - Cathode laser 2 ps Gaussian, cathode with 0.5 mm.mrad/mm thermal emittance
  - No beam aperture is used

	Beam at sample	'Single shot' (irreversible UED)	'High coherence' (micro-nano UED)	Unit
	Energy (tunable)	~	-4	MeV
	Wavelength (tunable)	~	-0.3	pm
	Bunch length (FWHM)	<	50	fs
	Pulse rate (tunable)	10-	~10 <sup>4</sup>	pulse/s
	Electron per pulse	~100 (10 <sup>6</sup> e⁻)	~0.1 (10 <sup>3</sup> e⁻)	fC/pulse
	Normalized emittance	20	0.2	nm.rad
	Beam rms size at sample	100	1	um
Т	ransverse coherence length		2	nm
	Source size at cathode	200	2	μm
	PITZ gun L-bar Bun velocit	nd booster picher for v bunching Q1/2/3/4	asma cell High1 mple Diffra	.Scr5
	<	~9 meter	dete	

## **Preparation of first static MeV electron diffraction test at PITZ**

Collaboration between PITZ, Max-Born-Institute (MBI) and Fritz-Haber-Institute (FHI)

- DESY/PITZ: Installation, beam experiment, ...
- MBI: Sample substrate, Au sample, EMCCD + Lens, beam experiment, ...
- FHI: WS<sub>2</sub> sample, diffraction pattern analysis, ...



## **Preparation of first static MeV electron diffraction test at PITZ**



+Actuator (PITZ)



Sample substrate

(MBI)

EMCCD camera (MBI)



EMCCD camera Installed at PITZ beamline

Courtesy H. Qian

## PITZ 1<sup>st</sup> test vs FHI table-top electron diffractometer

Comparison of diffraction patterns



Comparison of beam parameters

	FHI typical	PITZ 1st test	
beam energy	<0.1	~4	MeV
wavelength	3.7	0.27	pm
coherence length	2.8	1.9	nm
beam size at sample	~0.1	~1	mm
beam pulse duration	60~100	~2000	fs
bunch charge	1~5e3	~2e6	e/bunch
beam repetition rate	<4	<6	10 <sup>3</sup> pulse/sec
time resolution	200-300	~400 (estim.)	fs



#### Compared to FHI instrument

- Emittance  $\rightarrow$  a factor of 15 (by beam aperture)
- Pulse length → a factor of 20 (short laser or bunch compression)
- $\circ$  Time resolution  $\rightarrow$  to be demonstrated
- Higher voltage, higher bunch charge

Courtesy H. Qian

## Conclusions

## THz generation and UED at PITZ

- PITZ: developments on sources of high brightness electron beams and their applications
- PITZ = prototype of accelerator based IR/THz source for pump-probe experiments at the European XFEL
- High-gain THz SASE FEL at a PITZ-like accelerator
  → mJ THz pulses expected
- Proof-of-principle experiment on THz SASE FEL at PITZ:
  →LCLS-I undulator in the PITZ tunnel annex
  →S2E simulations for 4nC (~200A) → ~0.5mJ @ 100um
  →Experimental studies with Gaussian photocathode laser pulses
  → First THz Radiation Generated at PITZ
- Ultrafast Electron Diffraction (UED) at PITZ
  → first static MeV electron diffraction tests

# Thank you!